

The Tangerine Project

TowArds Next GEneration SilicoN DEtectors



Manuel Alejandro Del Rio Viera on behalf of the Tangerine Project

PIER Detector Workshop

June 1st 2023

HELMHOLTZ

UNIVERSITÄT **BONN**



DESY.



The Tangerine Project

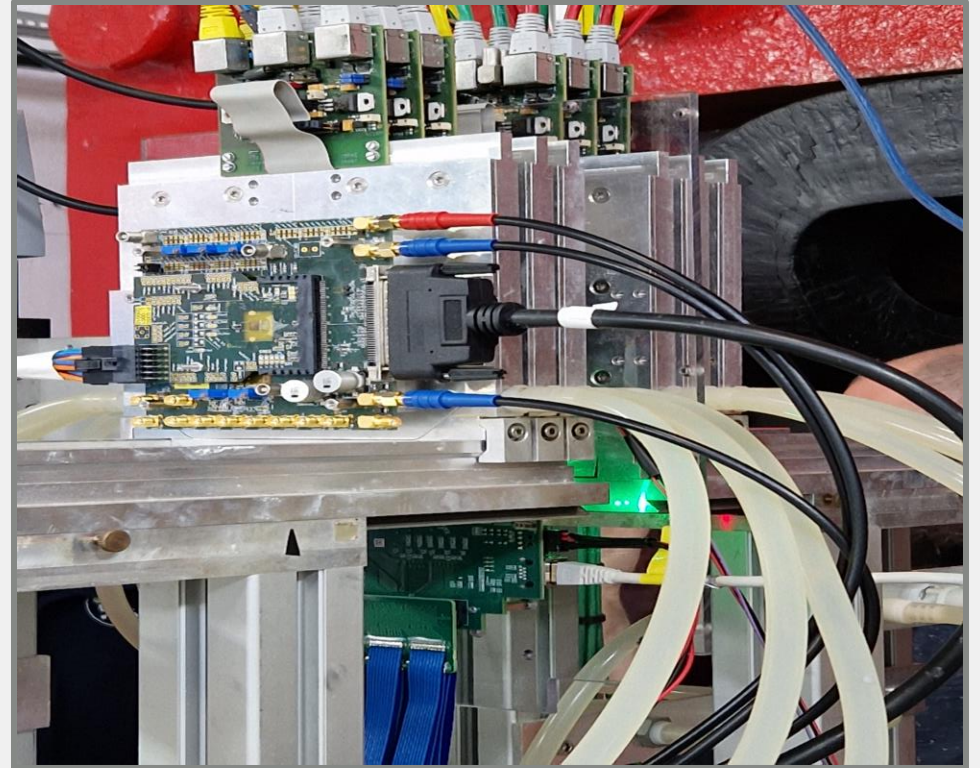
TowArds Next GEneration SilicoN DEtectors

Goal: Develop the next generation of monolithic silicon pixel detectors using a 65 nm CMOS imaging process

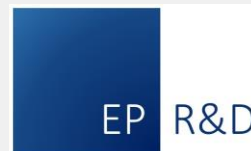
- Trackers for future e^+e^- Colliders
- Reference detector at DESY-II test beam upgrade



- ❖ A Helmholtz Innovation Pool and DESY project
- ❖ The project started in 2020
- ❖ Part of the **Work Package 1 (WP1)**: Monolithic pixel detectors in novel CMOS imaging technology
- ❖ Supported by **CERN EP R&D**



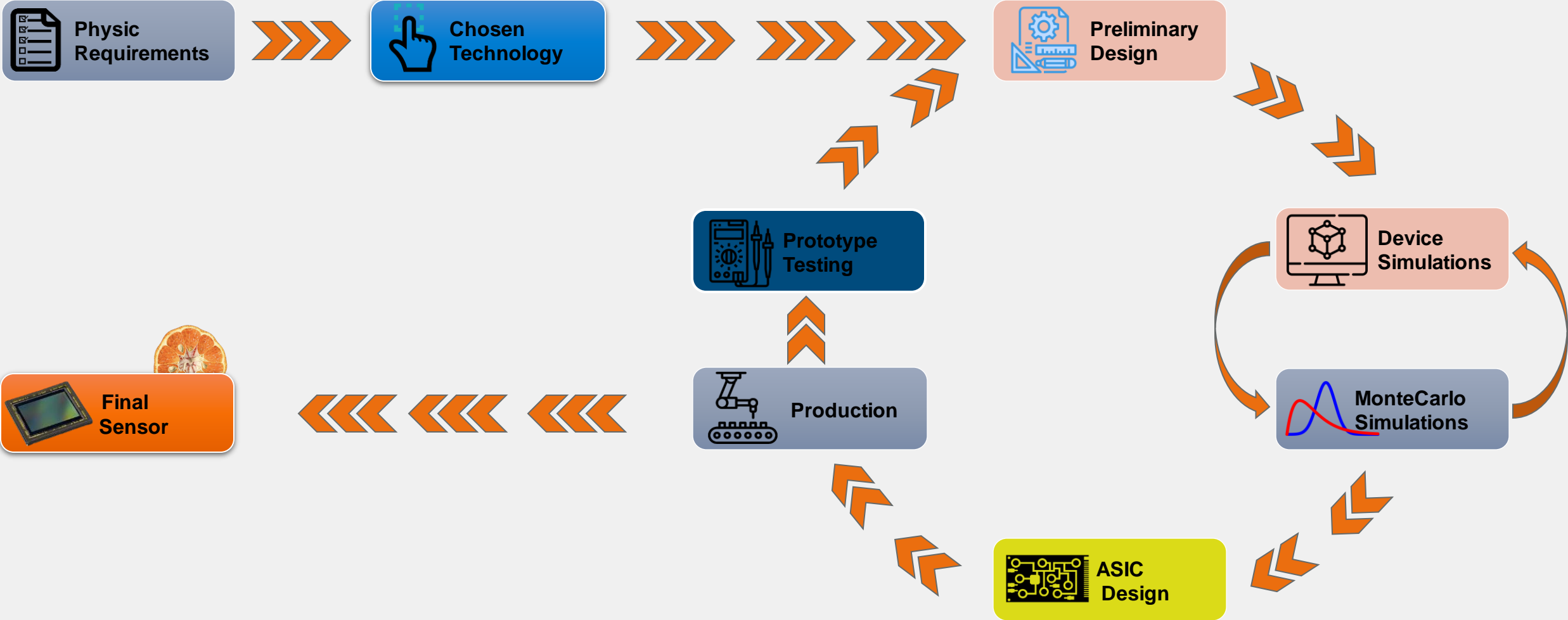
MIMOSA Telescope at the DESY II Facility



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Our Tangerine Workflow

Involved in all steps of developing a Silicon Detector



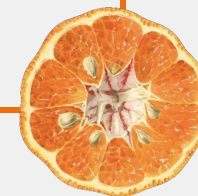
Physic Requirements

in a 65 nm CMOS technology



Tangerine Chip Requirements:

- Material budget $< 0.05\% X/X_0 \sim 50 \mu\text{m}$ silicon
- Single-point resolution $\sim 3\mu\text{m}$
- Time resolution $\sim 1\text{-}10 \text{ ns}$
- Rate capabilities: **1 MHz particle rate**
- Granularity $< 25 \mu\text{m} \times 25 \mu\text{m}$



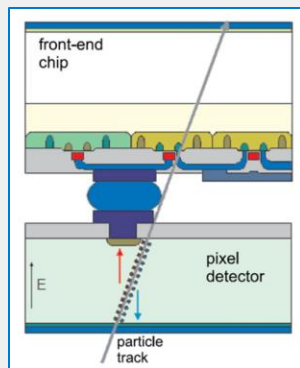
	(HL-) LHC (ATLAS/CMS)	Lepton Colliders
Material budget	$10\% X_0$	$< 1\% X_0$
Single-point resolution	$\sim 15 \mu\text{m}$	$\leq 3 \mu\text{m}$
Time resolution	25 ns	$\sim \text{ps} - \text{ns}$
Granularity	$50 \mu\text{m} \times 50 \mu\text{m}$	$\leq 25 \mu\text{m} \times 25 \mu\text{m}$
Radiation tolerance	$O(10^{16} n_{\text{eq}} / \text{cm}^2)$	$< 10^{11} n_{\text{eq}} / \text{cm}^2$

Monolithic Active Pixel Sensors (MAPS)

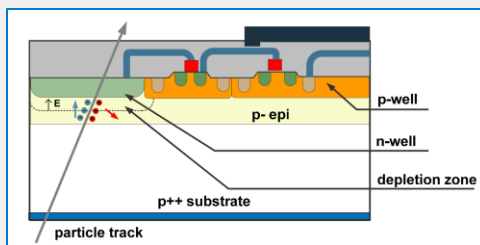
in a 65 nm CMOS technology



Hybrid



Monolithic

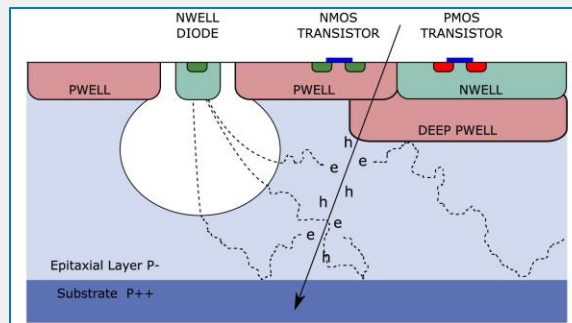


N. Werners/Univ. of Bonn

From Hybrid to Monolithic

- Reduced material budget
- Reduced complexity
- Reduced production cost
- Smaller pixels

ALPIDE ALICE ITS Upgrade



Small Collection Electrode

- Reduce noise and power consumption ($\sim 40 \text{ mW/cm}^2$)
- Better spatial resolution $\sim 5 \mu\text{m}$

180 nm
CMOS

65 nm
CMOS

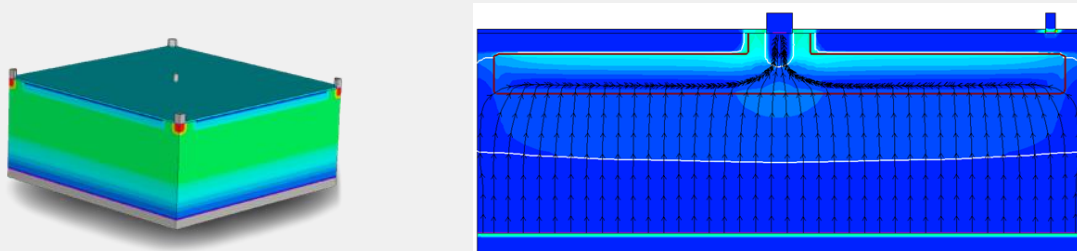
180 nm to 65 nm

- Higher logic density
 - ✓ Smaller pixels
 - ✓ Better in pixel functionality
- Further decrease in power consumption



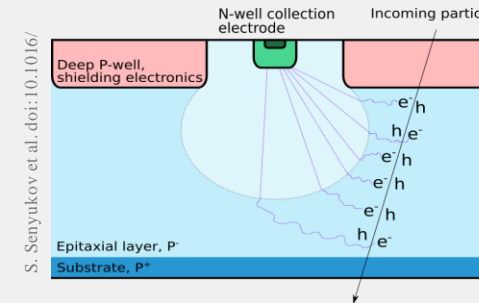
Simulations provide important insight into performance parameters of the sensor.

- **Standard layout:**
 - Small depleted volume
 - Collection by drift and diffusion
 - Lower efficiency but better spatial resolution due to charge sharing
- **N-blanket layout:**
 - Larger depleted region
 - Collection mostly by drift
 - Higher efficiency
- **N-gap layout:**
 - Lateral component of electric field
 - Even better efficiency and collection time



Monolithic Active Pixel Sensors (MAPS)

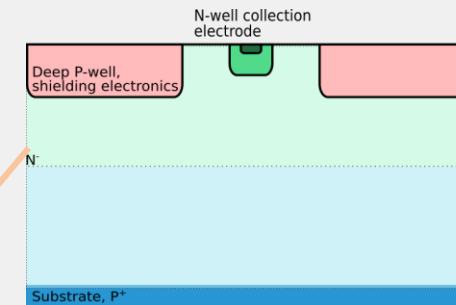
Standard



Small Collection Electrode

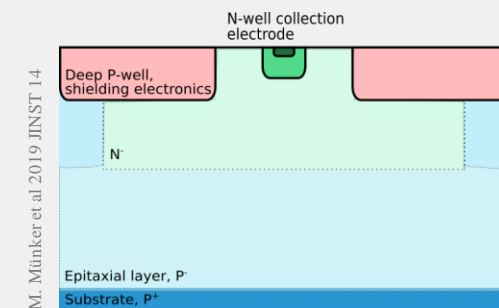
N-Blanket

Continuous N-type Implant



Increase the depleted region

N-Gap



Gap in Continuous N-type Implant

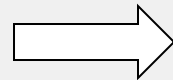
Speed up charge collection

Monte Carlo Simulations

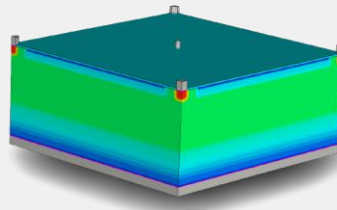
Transient Simulations - Full Detector Response

The **static** Electric Field, Doping Concentration and Electrostatic Potential Profiles are converted and imported into **Allpix Squared (APSQ)**:

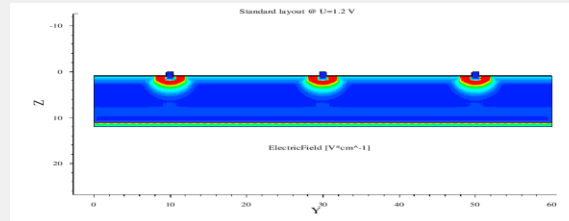
- Combining the best of both: **High statistics** and **accurate field modeling**
- Same conditions as lab and test beam setup are simulated
- Simulation results are **compared with measurements** of prototypes



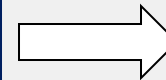
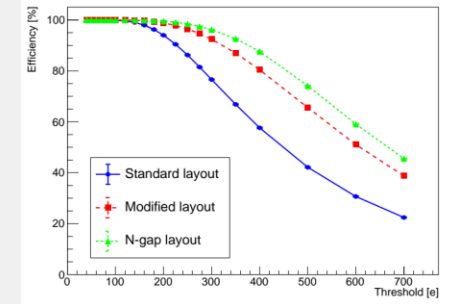
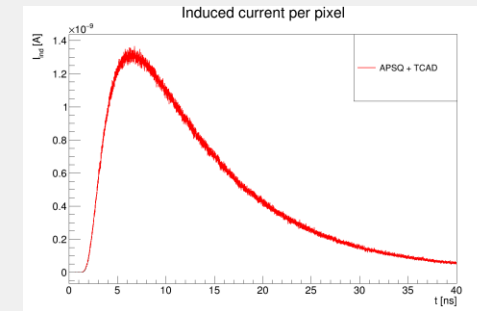
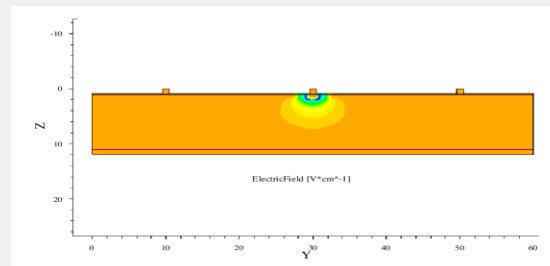
Generic Doping Profiles

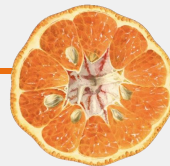


Electric Field

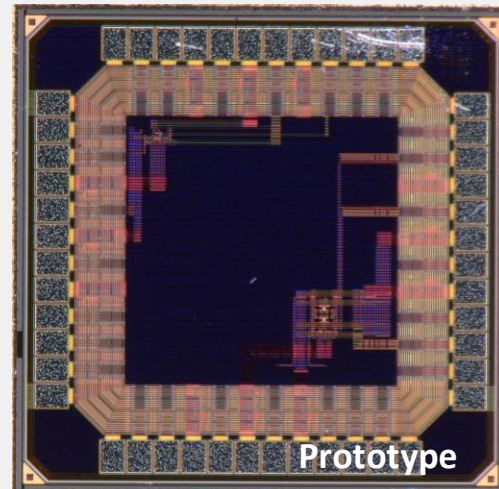
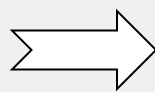
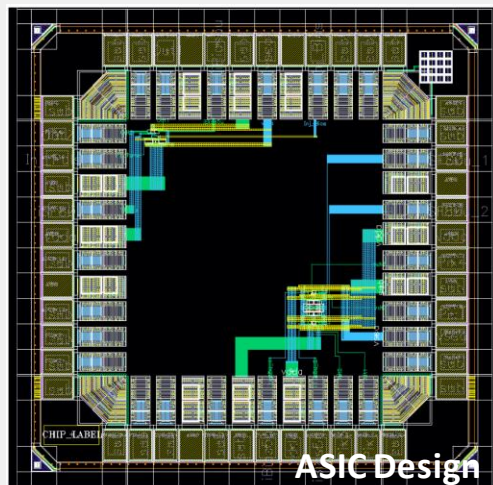


Weighting Potential



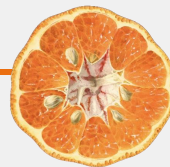


Multi-Layer Reticle 1 (MLR1) production

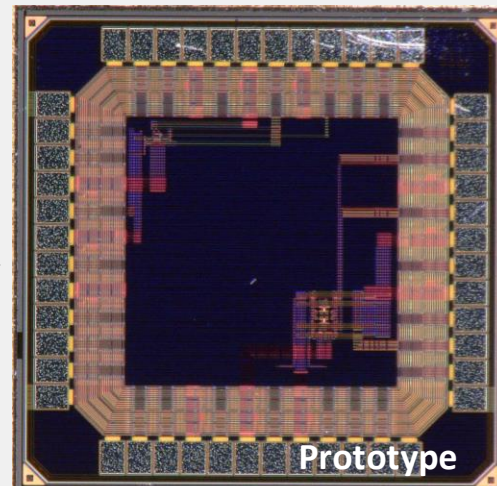
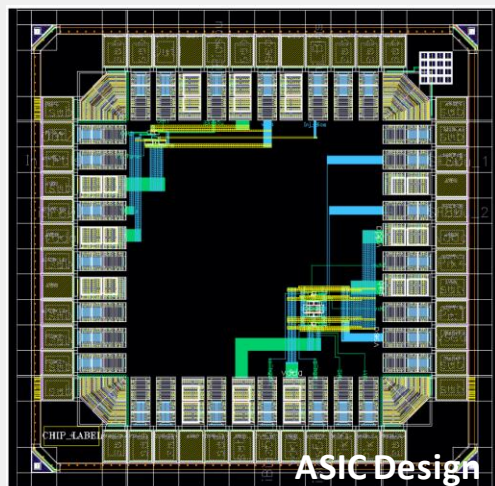


DESY MLR1:

- Entirely developed at DESY
- Test structures for Charge Sensitive Amplifier (CSA) characterization developed at DESY
- Block of 2x2 16 μm pixels with an analogue readout for pixel characterization



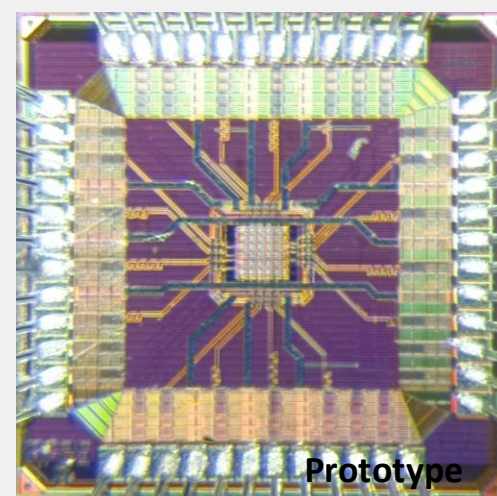
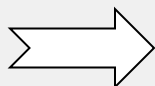
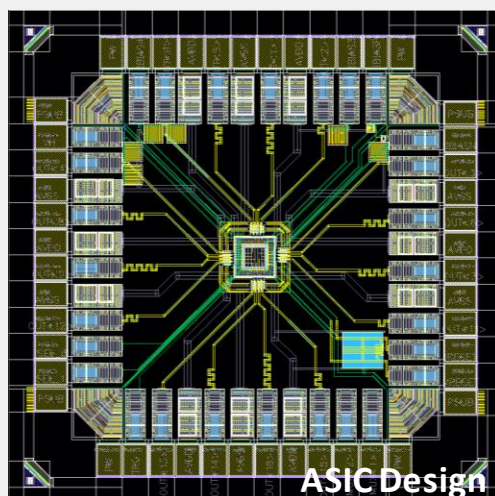
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Analogue Pixel Test Structures (APTS)

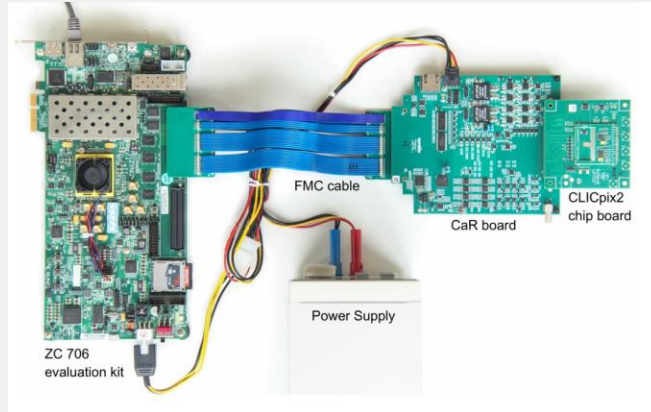


Analogue Pixel Test Structures (APTS):

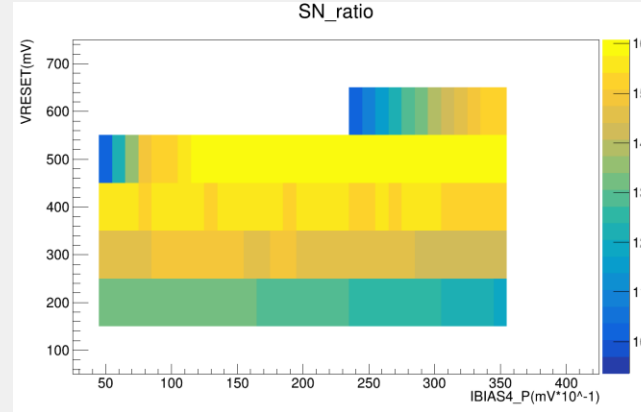
- Designed at CERN (DESY involved in the lab and TB characterization)
- 4x4 pixels structure with analogue output
- Different sensor pitches and layouts

Laboratory Activities

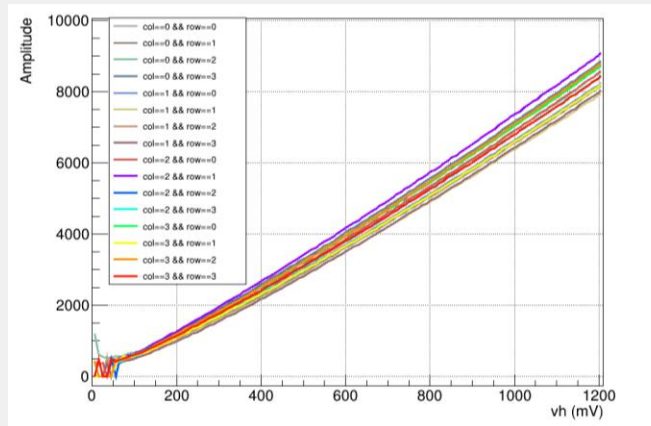
DAQ development, TB preparation, Calibration



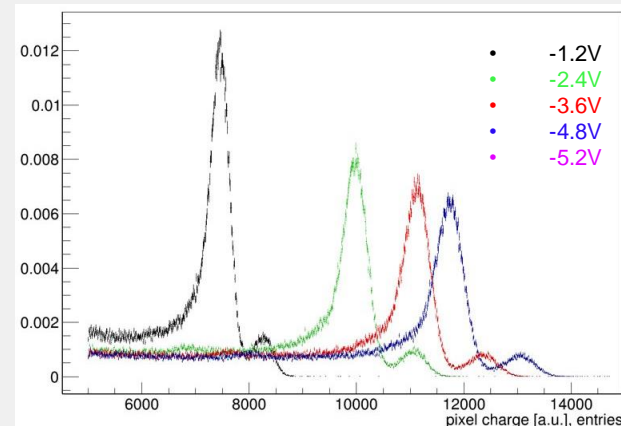
Caribou DAQ System



Example of parameters scan



Charge injection study



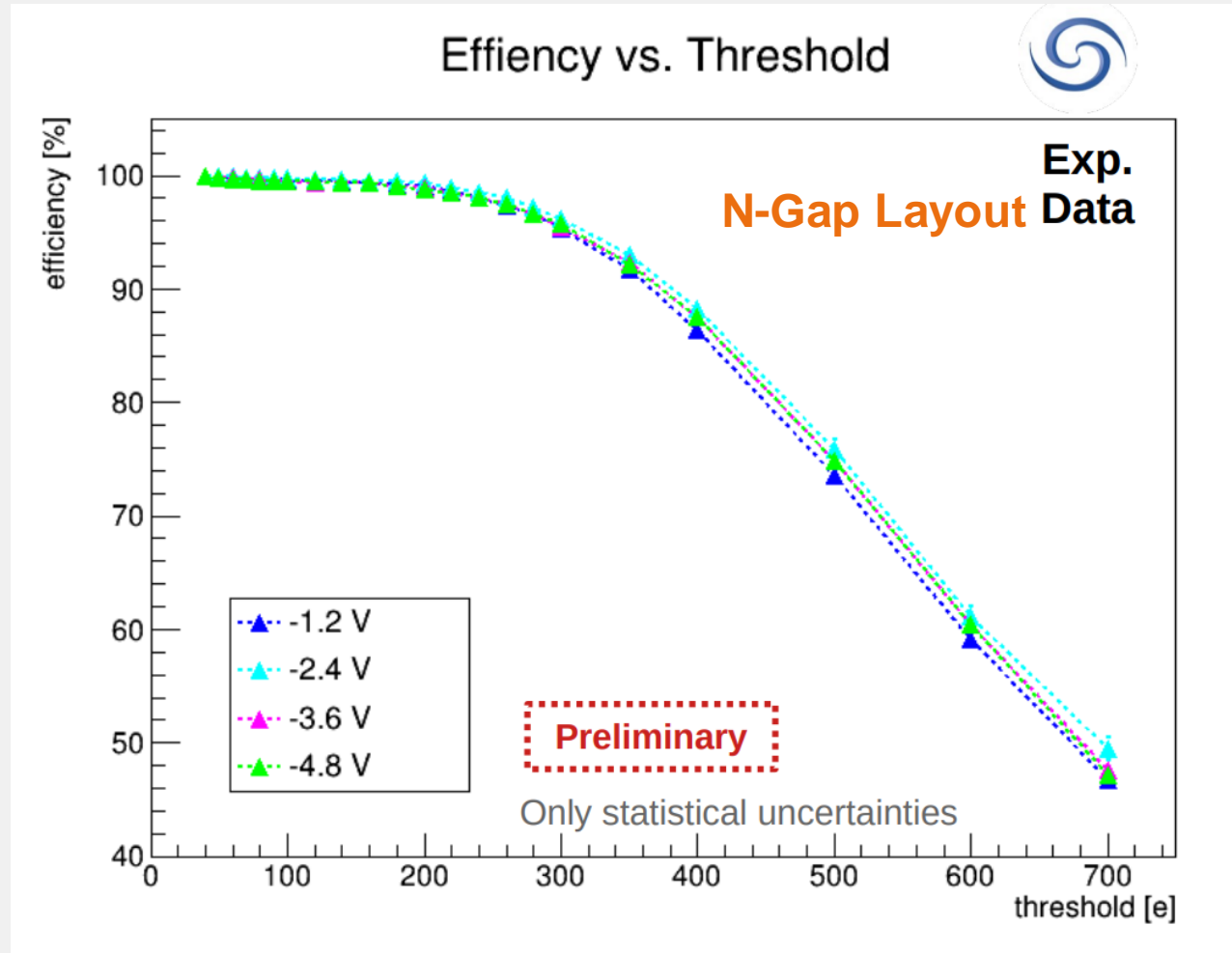
Fe-55 studies on APT S

- Development and testing of **data acquisition system**
- Optimization of front-end **operation parameters**
- Studies with charge injection and radioactive sources for **gain calibration**
- **Integration and testing** in preparation for Test Beam campaigns



Test Beam Results

N-Gap Layout

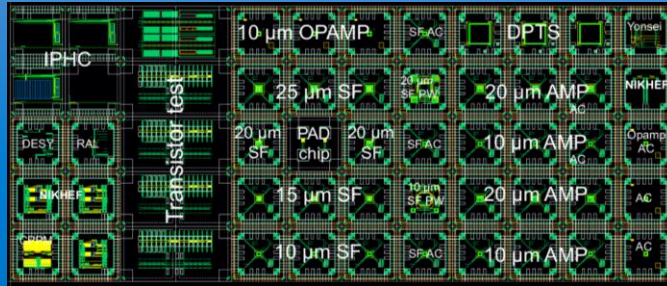


@Adriana Simancas

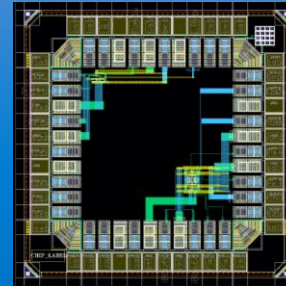
- ✓ No significant impact between voltages
- ✓ Similar trend between different voltages
- ✓ Valuable set of measurements to validate our simulations

Timeline and next to come

From MLR1 to ER1

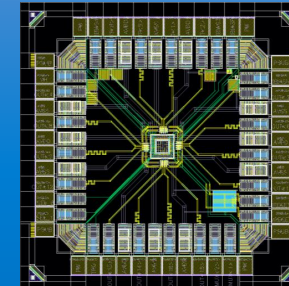


MLR1 reticle



DESYS Chip V1

2021

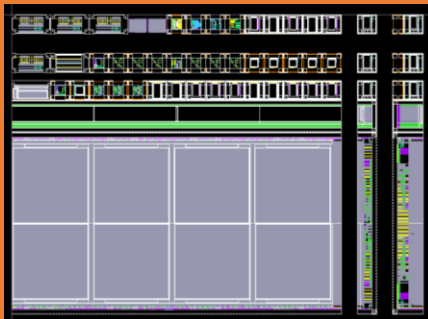


APTS

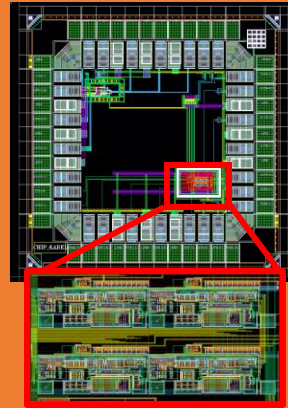
2022



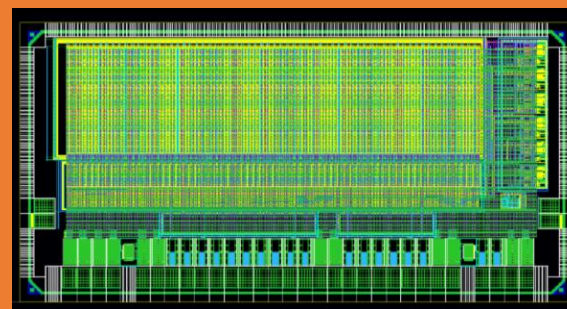
Engineering Run 1 (ER1) in Production



ER1 reticle



DESYS Chip V2



H2M Chip

2023

DESYS Chip V2

- 2x2 pixel ($35 \times 25 \mu\text{m}^2$) with all-in-pixel functionality
- External access to CSA and discriminator output
- N-gap layout with $2.5 \mu\text{m}$ and $4 \mu\text{m}$ gap
- Single Front-End with charge Injection

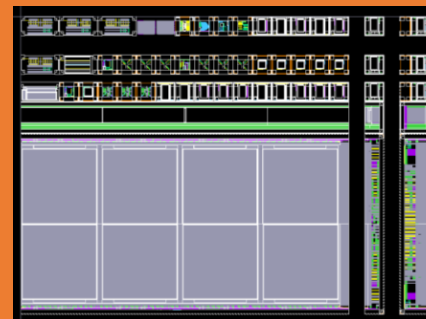
H2M (Hybrid-To-Monolithic)

- Collaboration of DESY, CERN and IFAE
- $3 \times 1.5 \text{ mm}^2$, 64×16 square pixel, $35 \mu\text{m}$ pitch
- 8-bit counter per pixel
- 4 acquisition modes (ToA, ToT, counting, binary RO)

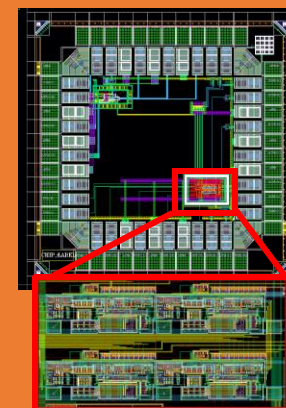
- The Tangerine group investigates the **65 nm CMOS imaging** technology
- **Upgrading our DESY II MIMOSA Telescope** is the primary goal of the project
- We are involved in **all stages of development and testing** of the prototypes
- Device and Monte Carlo simulations reduce **production iterations** (and costs)
- Simulation results are **compared with data** from TB and laboratory measurements
- The **next prototypes** are expected at DESY in Summer-Fall 2023



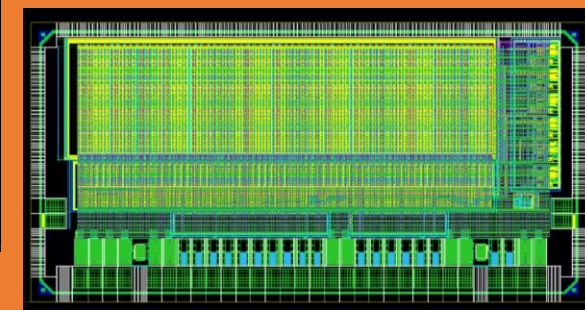
Coming in Q2-Q3 2023



ER1 reticle



DESY Chip V2



H2M Chip

2023

Thank you for your time!



Contact

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